NSN 5961-00-260-1669

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-260-1669 **Inclosure Material:** Metal **Overall Length:** 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 25.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 300.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 40.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

NSN 5961-00-260-1669 Transistor - Page 2 of 2



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